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## Multiferroics under strong magnetic fields

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We have systematically investigated electric/magnetic phase diagram of a series of multiferroic crystals  $R\text{Mn}_2\text{O}_5$  ( $R=\text{Tb}$ ,  $\text{Dy}$ ,  $\text{Bi}$ , and  $\text{Y}$ ) through the magnetization ( $M$ ), dielectric constant ( $\epsilon$ ), electrical polarization ( $P$ ) and specific heat ( $C_p$ ) measurements down to 0.6 K and under static and pulsed magnetic field ( $H$ ) up to 45 tesla (T) at NHMFL. Comparative studies of the phase diagram reveal several unprecedented findings: (1) phase evolution of the incommensurate antiferromagnetic Mn  $d$  spin ordering and related magneto-dielectric effects up to 33 T, (2) a new high field phase coupled to an incommensurate Mn  $d$  spin ordering appearing around 20 T, (3) phase evolution coupled to rare earth  $f$ -spin ordering and resultant polarization changes, and (4) significant modification of phase boundaries due to strong  $d$ - $f$  spin interaction. Based on the determined electric/magnetic phase diagram, we explain how the exchange striction mechanism can induce large polarization at high field region above 20 T in these series of  $R\text{Mn}_2\text{O}_5$  compounds. In the second part, we particularly discuss the intriguing electric/magnetic signals of  $\text{BiMn}_2\text{O}_5$ . At low temperatures below 5 K,  $\text{BiMn}_2\text{O}_5$  exhibits a single magnetic-field-induced transition near  $H_c \sim 18$  T as evidenced by a sharp increase in magnetization. Interestingly,  $\epsilon$  vs  $H$  curves show a sharp peak at  $H_c$ , of which magnitude systematically increases as temperature approaches proximity to a zero temperature. Furthermore,  $P$  changes its sign with increasing  $H$  from positive to negative at  $H_c$  without any hysteresis in  $H$  so that  $H_c$  coincides with the magnetic field at which  $P=0$ . The trajectory of which above three transitions occur follows the scaling relation  $T_c(H) \sim (H-H_c)^\alpha$  with  $\alpha=1/2$ . The shape of  $C_p$  versus  $H$  curve indicates that a magnetic-field-induced transition is close to the 2<sup>nd</sup> order down to  $\sim 0.6$  K which is consistent with the absence of hysteresis in  $M$ ,  $\epsilon$ , and  $P$  measurements. Temperature dependent  $\epsilon$  measurements under fixed magnetic field (Fig. 1) near  $H_c$  reveal that  $\epsilon$  increases systematically as  $T$  decreases to  $\sim 4$  K and slightly decreases down to 0.6 K, as similarly observed in quantum paraelectric  $\text{SrTiO}_3$ . All of these observations suggest an interesting possibility that  $\text{BiMn}_2\text{O}_5$  can be a unique system to exhibit quantum fluctuation of ferroelectricity tuned by magnetic field.

In close collaboration with : J. W. Kim, S. Y. Haam, Y. S. Oh, T. H. Kim, N. Hur, S. Park, S.-W. Cheong, J. H. Han, P. A. Sharma, N. Harrison, and A. Migliori

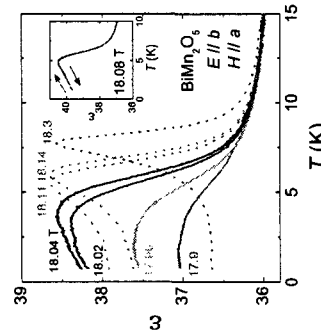


Fig. 1.  $\epsilon$  vs  $T$  curve near  $H_c=18$  T.

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Magnetic properties in  $\text{RfTiO}_3$  thin filmsC. U. Jung\*<sup>1</sup>

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$\text{RfTiO}_3$  ( $R = \text{Eu}, \text{Y}$ ) thin films were grown by using a pulsed laser deposition. The suitable choice of substrate as well as reducing growth condition allowed us to grow the epitaxial  $\text{YTiO}_3$  thin films. The  $\text{YTiO}_3$  film exhibited a clear ferromagnetic transition around 30 K with a saturation magnetization of about  $0.7 \mu\text{B}/\text{Ti}$ . [1] Recently, novel magnetic and electric phase control in epitaxial  $\text{EuTiO}_3$  thin films was predicted from first principles calculation. [2] To verify this prediction,  $\text{EuTiO}_3$  thin films were grown on various kinds of substrates with different lattice mismatch and their structural and magnetic properties were investigated.

## REFERENCES

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